NSN 5962-01-276-9907



Memory Microcircuit - Page 1 of 1 View Online at https://aerobasegroup.com/nsn/5962-01-276-9907 **Body Length:** 52.3 millimeters **Body Width:** 14.7 millimeters **Body Height:** 5.1 millimeters **Maximum Power Dissipation Rating:** 500.0 milliwatts **Operating Tempurature Range:** +0.0/+70.0 degrees celsius Storage Tempurature Range: -65.0/+150.0 degrees celsius **Features Provided:** Hermetically sealed and burn in and programmable and w/clock **Inclosure Material:** Ceramic **Inclosure Configuration:** Dual-in-line **Output Logic Form:** Transistor-transistor logic **Input Circuit Pattern:** 27 input **Terminal Surface Treatment:** Solder Voltage Rating And Type Per Characteristic: 7.0 volts power source **Time Rating Per Chacteristic:** 135.00 nanoseconds propagation delay time, low to high level output and 135.00 nanoseconds propagation delay time, high to low level output **Memory Device Type:** Pal **Test Data Document:** 96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.). **Terminal Type And Quantity:** 40 printed circuit Shelf Life: N/a **Unit Of Measure:**

Fiig: A458a0

Demilitarization: Yes - demil/mli